



SEB551V-30 Schottky barrier diode

Revision:A

Features

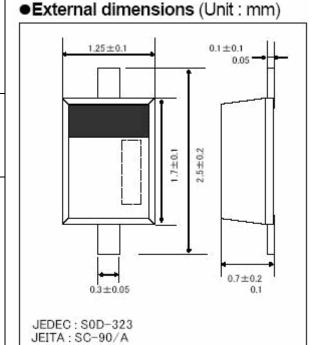
- Small mold type. (UMD2)
- Low VF
- High reliability

Applications

High frequency rectification

Construction

Silicon epitaxial planar



Absolute maximum ratings (Ta=25℃)

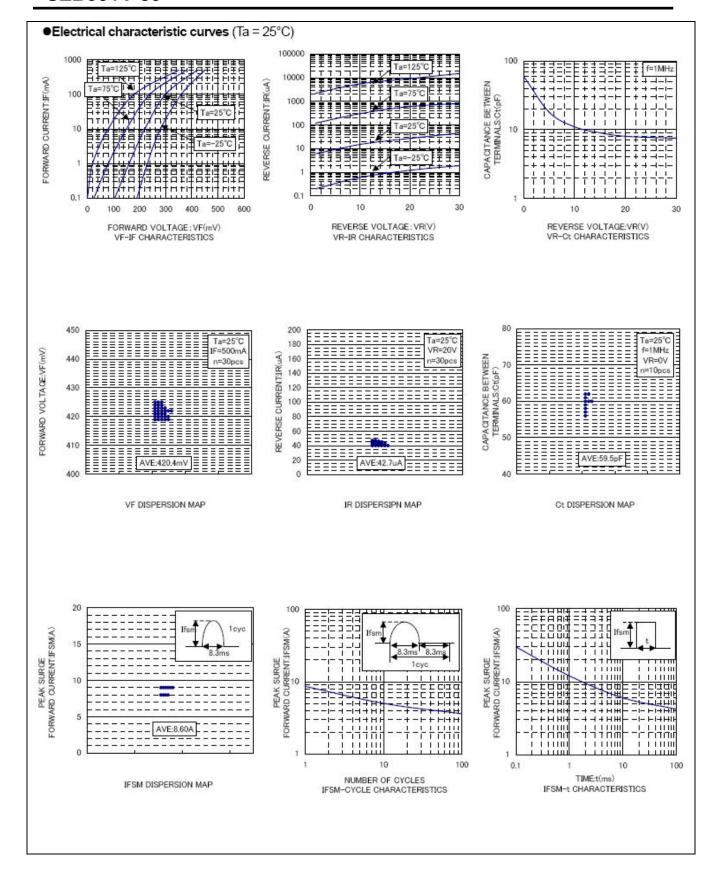
Parameter	Symbol	Limits	Unit
Reverse voltage (repetitive peak)	V_{RM}	30	V
DC reverse voltage	V_R	20	V
Average rectified forward current	Ιο	500	mA
Forward peak surge current (60Hz 1cyc.)	I _{FSM}	2	Α
Junction temperature	Tj	125	$^{\circ}$ C
Storage temperature	T_{stg}	-40 to +125	${\mathbb C}$

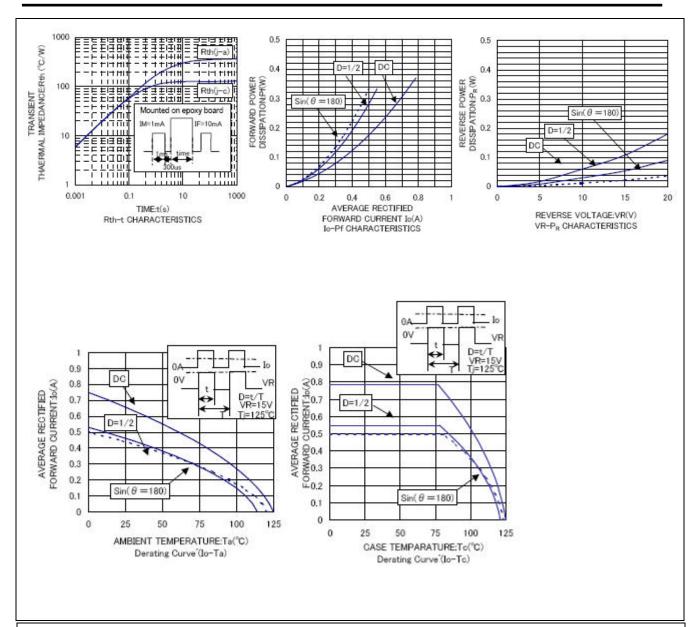
^{* 60}Hz, 1△

Electrical characteristics (Ta=25℃)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V_{F1}	_	_	0.36	V	I _F =100mA
	V_{F2}	_	_	0.47	V	I _F =500mA
Reverse current	I _R	_	_	100	uA	V _R =20V

Please pay attention to static electricity when handling.





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